

RoHS Compliant Product

Features

- 1) Low $V_{CE(sat)}$.
- 2) Excellent DC current gain characteristics
- 3) Complements the 2SD2118

● Absolute maximum ratings ($T_a=25^\circ\text{C}$)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V _{CBO}	−30	V
Collector-emitter voltage		V _{CEO}	−20	V
Emitter-base voltage		V _{EBO}	−6	V
Collector current		I _C	−5	A(DC)
			−10	A(Pulse) *1
Collector power dissipation	2SB1386	P _C	0.5	W
			2	W *2
	2SB1412		1	W
			10	W(T _C =25°C)
	2SB1326		1	W *3
Junction temperature		T _j	150	°C
Storage temperature		T _{stg}	−55~+150	°C

*1 Single pulse, $P_w=10\text{ms}$

*2 When mounted on a $40\times 40\times 0.7\text{ mm}$ ceramic board.

*3 Printed circuit board glass epoxy board 1.6 mm thick with copper plating 100mm^2 or larger.

● Electrical characteristics ($T_a=25^\circ\text{C}$)

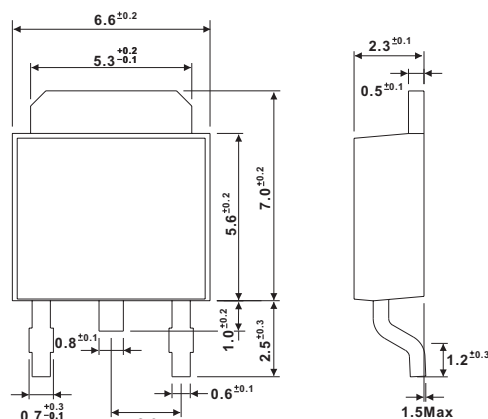
Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage		BV_{CBO}	-30	-	-	V	$I_C=-50\mu\text{A}$
Collector-emitter breakdown voltage		BV_{CEO}	-20	-	-	V	$I_C=-1\text{mA}$
Emitter-base breakdown voltage		BV_{EBO}	-6	-	-	V	$I_E=-50\mu\text{A}$
Collector cutoff current		I_{CBO}	-	-	-0.5	μA	$V_{CB}=-20\text{V}$
Emitter cutoff current		I_{EBO}	-	-	-0.5	μA	$V_{EB}=-5\text{V}$
Collector-emitter saturation voltage		$V_{CE(sat)}$	-	-	-1.0	V	$I_C/I_E=-4A/-0.1A$ *
DC current transfer ratio	2SB1386, 2SB1412	h_{FE}	82	-	390	-	$V_{CE}=-2\text{V}, I_C=-0.5\text{A}$ *
	2SB1326		120	-	390	-	*
Transition frequency		f_T	-	120	-	MHz	$V_{CE}=-6\text{V}, I_E=50\text{mA}, f=30\text{MHz}$
Output capacitance		C_{ob}	-	60	-	pF	$V_{CB}=-20\text{V}, I_E=0\text{A}, f=1\text{MHz}$

*Measured using pulse current.

● Packaging specifications and h_{FE}

Type	h_{FE}	Package	Taping		
		Code	T100	TL	TV2
		Basic ordering unit (pieces)	1000	2500	2500
2SB1386	PQR		○	-	-
2SB1412	PQR		-	○	-
2SB1326	QR		-	-	○

D-Pack



●Electrical characteristic curves

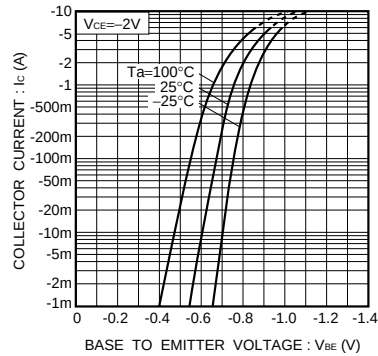


Fig.1 Grounded emitter propagation characteristics

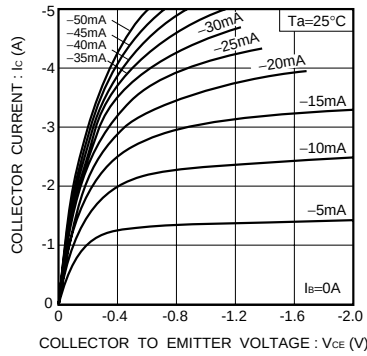


Fig.2 Grounded emitter output characteristics

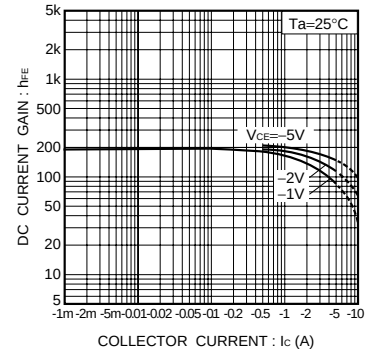


Fig.3 DC current gain vs. collector current (I)

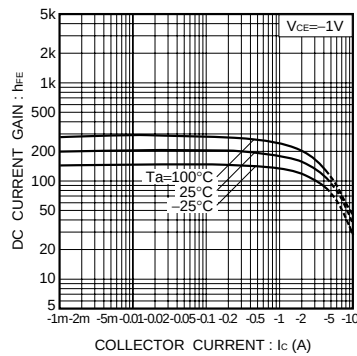


Fig.4 DC current gain vs. collector current (II)

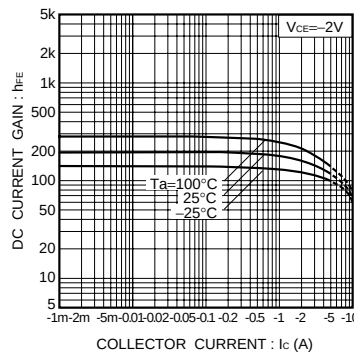


Fig.5 DC current gain vs. collector current (III)

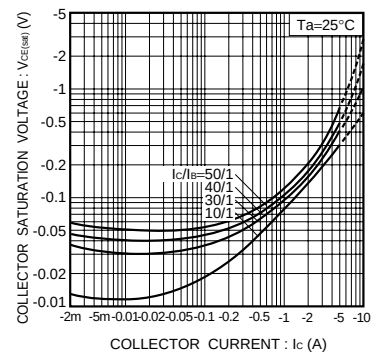


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

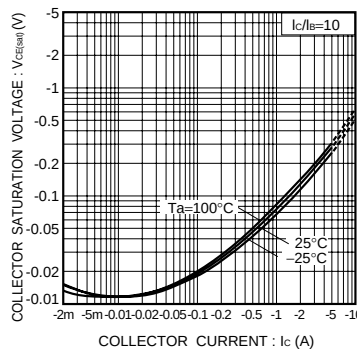


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

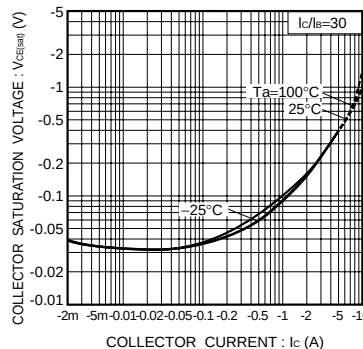


Fig.8 Collector-emitter saturation voltage vs. collector current (III)

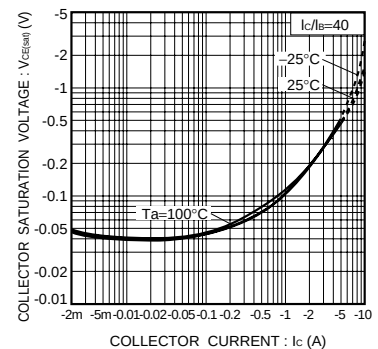


Fig.9 Collector-emitter saturation voltage vs. collector current (IV)

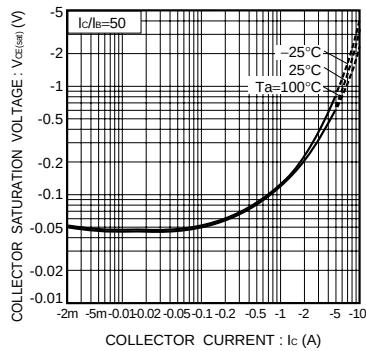


Fig.10 Collector-emitter saturation voltage vs. collector current (V)

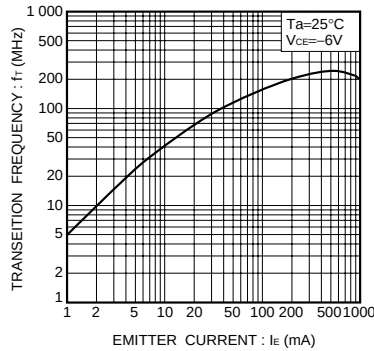


Fig.11 Gain bandwidth product vs. emitter current

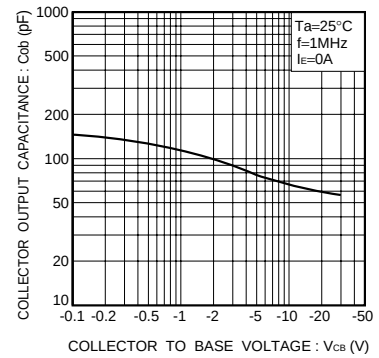


Fig.12 Collector output capacitance vs. collector-base voltage

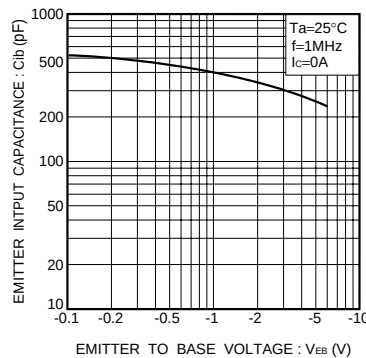


Fig.13 Emitter input capacitance vs. emitter-base voltage

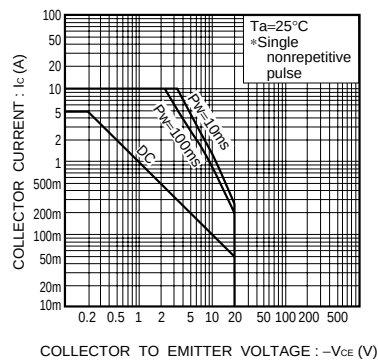


Fig.14 Safe operation area (2SB1412)